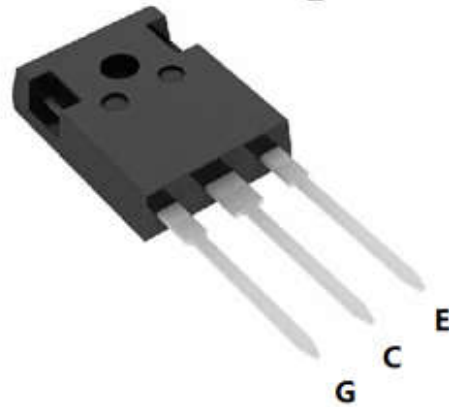
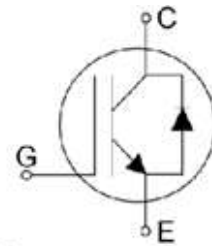


1200V /25A Trench Field Stop IGBT

- A High breakdown voltage to 1200V for improved reliability
- A Trench-Stop Technology offering :
 - A High speed switching
 - A High ruggedness, temperature stable
 - A Low V_{CEsat}
 - A Easy parallel switching capability due to positive temperature coefficient in V_{CEsat}
- A Enhanced avalanche capability

- A Uninterruptible Power Supplies
- A Solar inverter
- A Welding
- A PFC applications

| | | |
|--|--|--|
| | | |
| | | |
| | | |



| Product | Package | Packaging |
|---------------|---------|-----------|
| YGW25N120F1A1 | TO247 | Tube |

AA

| Parameter | Symbol | Value | Unit |
|---|-----------|------------|------------|
| Collector-Emitter Breakdown Voltage | V_{CE} | 1200 | V |
| DC collector current, limited by T_{jmax} $T_C = 25^\circ C$ $T_C = 100^\circ C$ | I_C | 50 25 | A |
| Diode Forward current, limited by T_{jmax} $T_C = 25^\circ C$ $T_C = 100^\circ C$ | I_F | 50 25 | A |
| Continuous Gate-emitter voltage | V_{GE} | ± 20 | V |
| Transient Gate-emitter voltage | V_{GE} | ± 30 | V |
| Turn off safe operating area $V_{CE} = 1200V$, $T_j = 150^\circ C$ | - | 75 | A |
| Pulsed collector current, $V_{GE} = 15V$, t_p limited by T_{jmax} | I_{CM} | 75 | A |
| Power dissipation , $T_j = 25^\circ C$ | P_{tot} | 260 | W |
| Operating junction temperature | T_j | -40...+150 | $^\circ C$ |
| Storage temperature | T_s | -55...+150 | $^\circ C$ |
| Soldering temperature, wave soldering 1.6mm (0.063in.) from case for 10s | - | 260 | $^\circ C$ |

A

| Parameter | Symbol | Max. Value | Unit |
|--|----------|------------|------|
| IGBT thermal resistance, junction - case | $R(j-c)$ | 0.48 | K/W |
| Diode thermal resistance, junction - case | $R(j-c)$ | 1.2 | K/W |
| Thermal resistance, junction - ambient | $R(j-a)$ | 40 | K/W |

($T_j = 25^\circ\text{C}$ unless otherwise specified) :

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|--------------------------------------|---------------|--|--------|------------|-------------|---------|
| Collector-Emitter breakdown voltage | BV_{CES} | $V_{GE}=0V, I_C=1mA$ | 1200 | - | - | V |
| Gate threshold voltage | $V_{GE(th)}$ | $V_{GE}=V_{CE}, I_C=250\mu A$ | 5.1 | 5.8 | 6.4 | V |
| Collector-Emitter Saturation voltage | $V_{CE(sat)}$ | $V_{GE}=15V, I_C=25A$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$ | - - | 2.0 2.5 | 2.5 - | V |
| Zero gate voltage collector current | I_{CES} | $V_{CE} = 1200V, V_{GE} = 0V$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$ | - - | <1 - | 100 1000 | μA |
| Gate-emitter leakage current | I_{GES} | $V_{CE} = 0V, V_{GE} = \pm 20V$ | - | - | 100 | nA |

A

Parameter Symbol Conditions Min. Typ

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|--------------------|-------------|--|------|------|------|------|
| Turn-on delay time | $t_{d(on)}$ | $V_{CC} = 600V, I_C = 25A,$ $V_{GE} = 0/15V,$ $R_g = 10\Omega$ | - | 35 | - | ns |
| Rise time | t_r | | - | 32 | - | ns |
| Turn-on energy | E_{on} | | - | 2.0 | - | |



Fig. 5 Switching loss vs. gate resistor

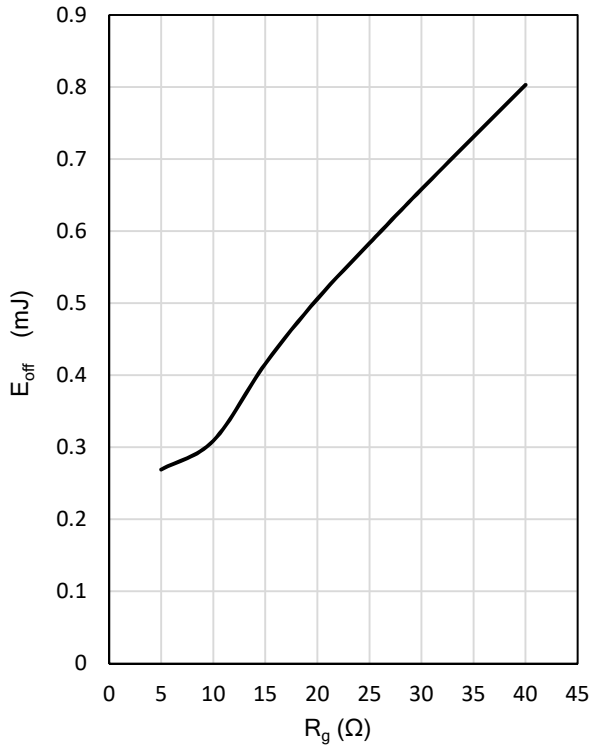


Fig. 6 Switching loss vs. collector current

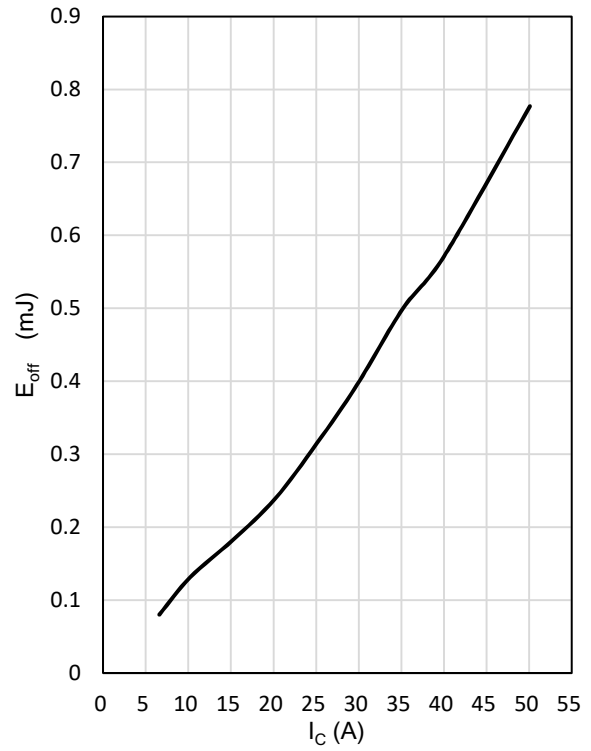
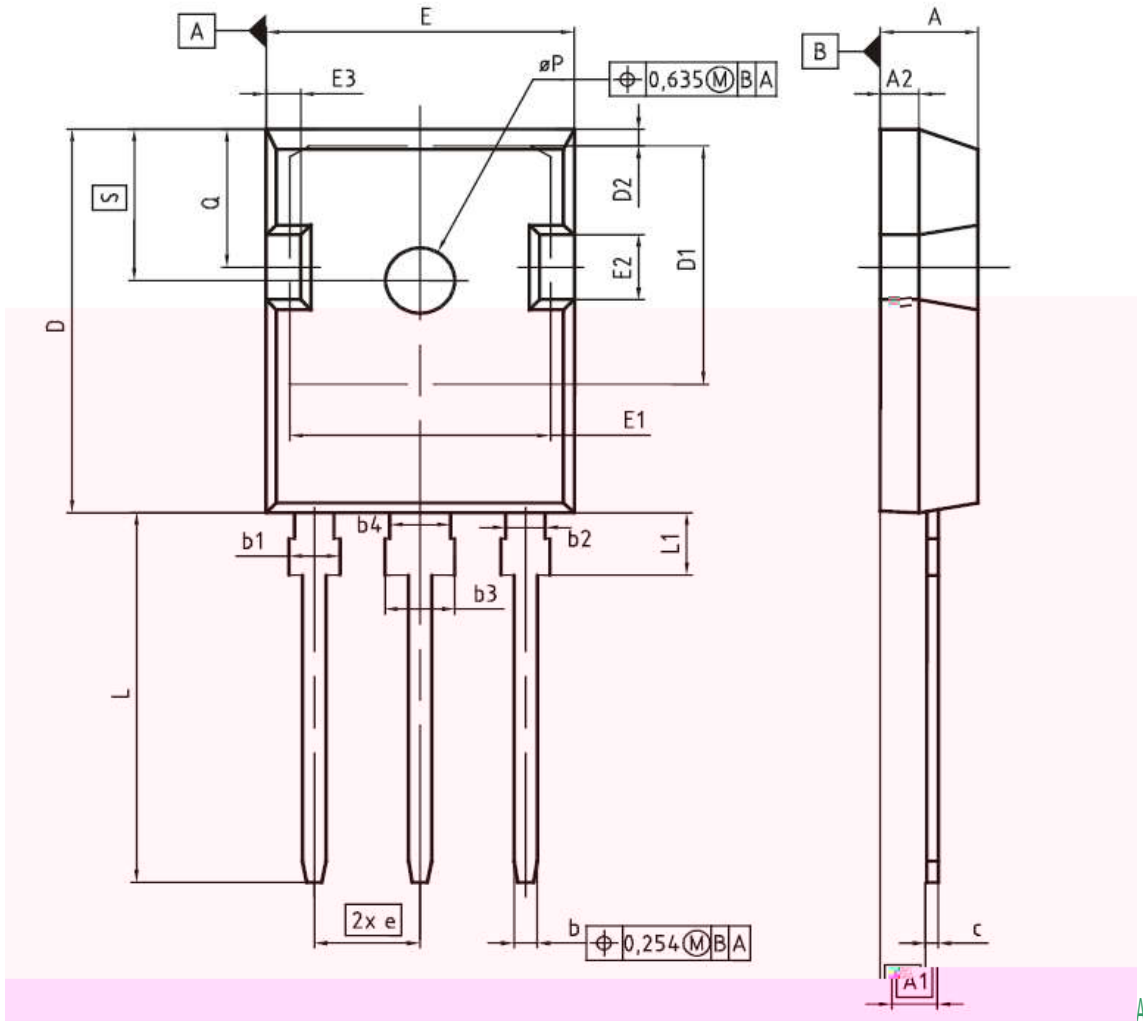


Fig. 7 Gate charge characteristics



Fig. 8 Capacitance characteristics

PG-TO247-3



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 4.83 | 5.21 | 0.190 | 0.205 |
| A1 | 2.27 | 2.54 | 0.089 | 0.100 |
| A2 | 1.85 | 2.16 | 0.073 | 0.085 |
| b | 1.07 | 1.33 | 0.042 | 0.052 |
| b1 | 1.90 | 2.41 | 0.075 | 0.095 |
| b2 | 1.90 | 2.16 | 0.075 | 0.085 |
| b3 | 2.87 | 3.38 | 0.113 | 0.133 |
| b4 | 2.87 | 3.13 | 0.113 | 0.123 |
| c | 0.55 | 0.68 | 0.022 | 0.027 |
| D | 20.80 | 21.10 | 0.819 | 0.831 |
| D1 | 16.25 | 17.65 | 0.640 | 0.695 |
| D2 | 0.95 | 1.35 | 0.037 | 0.053 |
| E | 15.70 | 16.13 | 0.618 | 0.635 |
| E1 | 13.10 | 14.15 | 0.516 | 0.557 |
| E2 | 3.68 | 5.10 | 0.145 | 0.201 |
| E3 | 1.00 | 2.60 | 0.039 | 0.102 |
| e | 5.44 (BSC) | | 0.214 (BSC) | |
| N | 3 | | 3 | |
| L | 19.80 | 20.32 | 0.780 | 0.800 |
| L1 | 4.10 | 4.47 | 0.161 | 0.176 |
| øP | 3.50 | 3.70 | 0.138 | 0.146 |
| Q | 5.49 | 6.00 | 0.216 | 0.236 |
| S | 6.04 | 6.30 | 0.238 | 0.248 |